

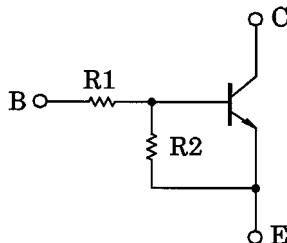
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1407,RN1408,RN1409

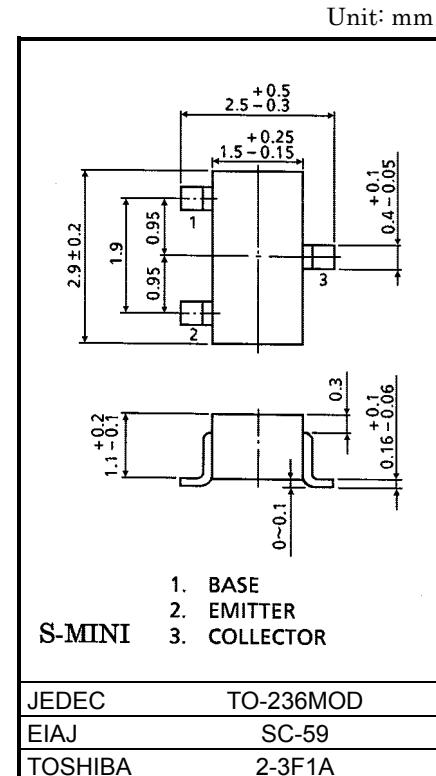
Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2407~RN2409

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1407	10	47
RN1408	22	47
RN1409	47	22



Weight: 0.012g

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	6	V
		7	
		15	
Collector current	I _C	100	mA
Collector power dissipation	P _C	200	mW
Junction temperature	T _j	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1407~1409	I_{CBO}	—	$V_{CB} = 50\text{V}, I_E = 0$	—	—	100	nA
		I_{CEO}		$V_{CE} = 50\text{V}, I_B = 0$	—	—	500	
Emitter cut-off current	RN1407	I_{EBO}	—	$V_{EB} = 6\text{V}, I_C = 0$	0.081	—	0.15	mA
	RN1408			$V_{EB} = 7\text{V}, I_C = 0$	0.078	—	0.145	
	RN1409			$V_{EB} = 15\text{V}, I_C = 0$	0.167	—	0.311	
DC current gain	RN1407	h_{FE}	—	$V_{CE} = 5\text{V}, I_C = 10\text{mA}$	80	—	—	—
	RN1408				80	—	—	
	RN1409				70	—	—	
Collector-emitter saturation voltage	RN1407~1409	$V_{CE}(\text{sat})$	—	$I_C = 5\text{mA}, I_B = 0.25\text{mA}$	—	0.1	0.3	V
Input voltage (ON)	RN1407	$V_I(\text{ON})$	—	$V_{CE} = 0.2\text{V}, I_C = 5\text{mA}$	0.7	—	1.8	V
	RN1408				1.0	—	2.6	
	RN1409				2.2	—	5.8	
Input voltage (OFF)	RN1407	$V_I(\text{OFF})$	—	$V_{CE} = 5\text{V}, I_C = 0.1\text{mA}$	0.5	—	1.0	V
	RN1408				0.6	—	1.16	
	RN1409				1.5	—	2.6	
Transition frequency	RN1407~1409	f_T	—	$V_{CE} = 10\text{V}, I_C = 5\text{mA}$	—	250	—	MHz
Collector Output capacitance	RN1407~1409	C_{ob}	—	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$	—	3	6	pF
Input resistor	RN1407	R1	—	—	7	10	13	kΩ
	RN1408				15.4	22	28.6	
	RN1409				32.9	47	61.1	
Resistor ratio	RN1407	R1/R2	—	—	0.191	0.213	0.232	—
	RN1408				0.421	0.468	0.515	
	RN1409				1.92	2.14	2.35	

